





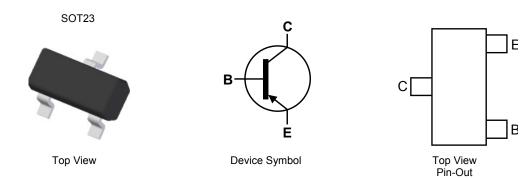
60V PNP MEDIUM POWER TRANSISTOR IN SOT23

Features

- BV_{CEO} > -60V
- I_C = -1A High Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- R_{SAT} = 295m Ω for a Low Equivalent On-Resistance
- hFE characterised up to -2A for high current gain hold up
- Complementary NPN Type: FMMT491
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: molded plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (23)
- Weight 0.008 grams (approximate)



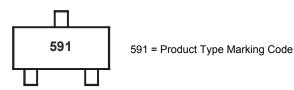
Ordering Information (Note 4)

| Part Number | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| FMMT591TA | AEC-Q101 | 591 | 7 | 8 | 3,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information







Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V_{CBO} | -80 | V |
| Collector-Emitter Voltage | V _{CEO} | -60 | V |
| Emitter-Base Voltage | V _{EBO} | -7 | V |
| Continuous Collector Current | lc | -1 | Α |
| Peak Pulse Current | I _{CM} | -2 | Α |
| Base Current | I _B | -200 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|--|-----------------------------------|------------------|------|------|
| Power Dissipation | (Note 5) | P _D | 500 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | | $R_{\theta JA}$ | 250 | °C/W |
| Thermal Resistance, Junction to Lead (Note 6) | | R _{0JL} | 197 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C | |

ESD Ratings (Note 7)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

Notes:

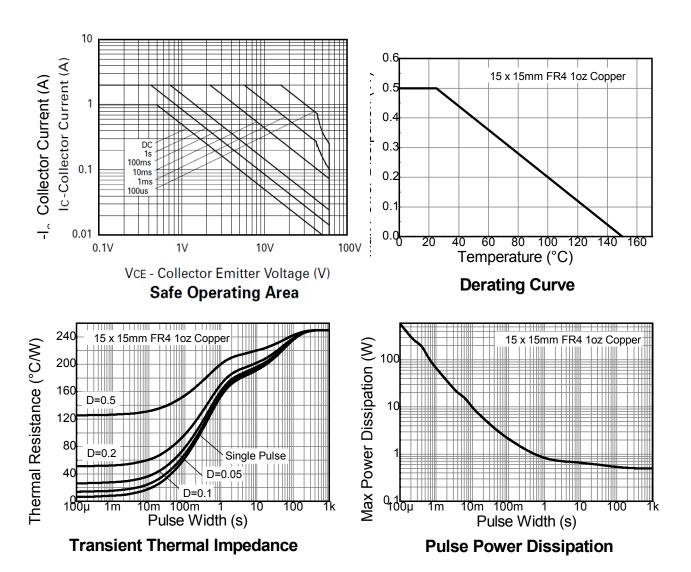
^{5.} For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

^{6.} Thermal resistance from junction to solder-point (at the end of the collector lead).

^{7.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information







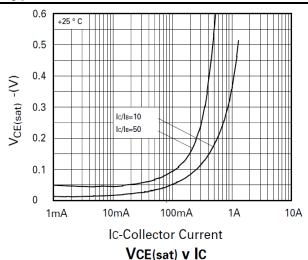
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

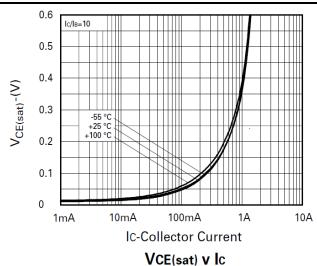
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|----------------------|------------------------|-------------------------|---------------|------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | -80 | _ | _ | V | I _C = -100μA |
| Collector-Emitter Breakdown Voltage (Note 9) | BV _{CEO} | -60 | _ | _ | V | I _C = -10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | -8.1 | _ | V | I _E = -100μA |
| Collector-Base Cutoff Current | I _{CBO} | _ | <1 | -100 | nA | V _{CB} = -60V |
| Emitter-Base Cutoff Current | I _{EBO} | _ | <1 | -100 | nA | V _{EB} = -5.6V |
| Collector-Emitter Cut-Off Current | I _{CES} | _ | <1 | -100 | nA | V _{CE} = -50V |
| Static Forward Current Transfer Ratio (Note 8) | h _{FE} | 100 100 80 15 | 220 175 155 40 | 300 — — | _ | I_{C} = -1mA, V_{CE} = -5V I_{C} = -500mA, V_{CE} = -5V I_{C} = -1A, V_{CE} = -5V I_{C} = -2A, V_{CE} = -5V |
| Collector-Emitter Saturation Voltage (Note 8) | V _{CE(SAT)} | _ | -155 -295 | -180 -350 | mV | I _C = - 500mA, I _B = -50mA I _C = - 1A, I _B = -100mA |
| Base-Emitter Saturation Voltage (Note 8) | V _{BE(SAT)} | _ | 965 | -1200 | mV | I _C = -1A, I _B = -100mA |
| Base-Emitter Turn-On Voltage (Note 8) | V _{BE(ON)} | _ | 830 | -1000 | mV | $I_C = -1A$, $V_{CE} = -5V$ |
| Transition Frequency | f _T | 150 | _ | _ | MHz | V _{CE} = -10V, I _C = -50mA, f = 100MHz |
| Output Capacitance | C _{obo} | _ | _ | 10 | pF | V _{CB} = -10V, f = 1MHz |

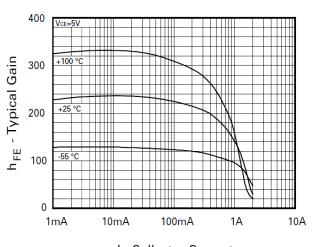
Note: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

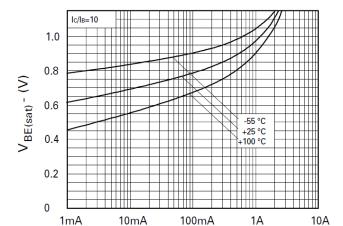


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



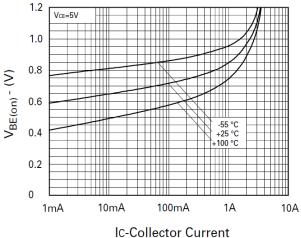






Ic-Collector Current **hFE V IC**

VBE(sat) v Ic

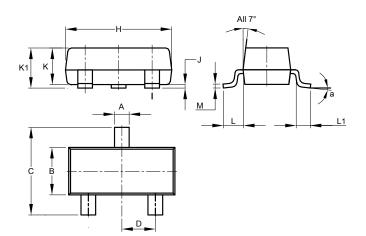


VBE(on) v IC



Package Outline Dimensions

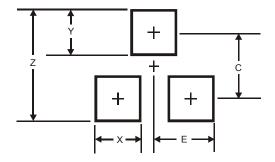
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT23 | | | | | |
|-------|----------------------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.37 | 0.51 | 0.40 | | |
| В | 1.20 | 1.40 | 1.30 | | |
| С | 2.30 | 2.50 | 2.40 | | |
| D | 0.89 | 1.03 | 0.915 | | |
| F | 0.45 | 0.60 | 0.535 | | |
| G | 1.78 | 2.05 | 1.83 | | |
| Н | 2.80 | 3.00 | 2.90 | | |
| J | 0.013 | 0.10 | 0.05 | | |
| K | 0.890 | 1.00 | 0.975 | | |
| K1 | 0.903 | 1.10 | 1.025 | | |
| L | 0.45 | 0.61 | 0.55 | | |
| L1 | 0.25 | 0.55 | 0.40 | | |
| М | 0.085 | 0.150 | 0.110 | | |
| а | 8° | | | | |
| All | All Dimensions in mm | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) | | |
|------------|---------------|--|--|
| Z | 2.9 | | |
| Х | 0.8 | | |
| Υ | 0.9 | | |
| С | 2.0 | | |
| E | 1.35 | | |





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